

LN....LZ

LN....	Opto					
LN 9014(B....D)	Si-N	Uni, ra, 30V, 0,1A, 0,3W, 120MHz	7e	BC 550	7a	
LN 9015(B....D)	Si-P	Uni, ra, 30V, 0,1A, 0,3W, 120MHz	7e	BC 560	7a	
LS 141(A,C)T,TB	OP-IC	Uni, Serie 741	T0-99	741/T0	T0-99	*
LS 141 CB	OP-IC	=LS 141(A,C)T: Fig. →	8-DIP	741/8-D	8-DIP	
LS 148(A,C)T,TB	OP-IC	Uni, Serie 748	T0-99	748/T0	T0-99	*
LS 148 CB	OP-IC	=LS 148(A,C)T: Fig. →	8-DIP	748/8-D	8-DIP	
LS 709 CB	OP-IC	=LS 709CTB: Fig. →	14-DIP	-	-	
LS 709(A,C)TB	OP-IC	Uni, Serie 709, ±18V	T0-99	-	-	
LS 4148	Si-Di	=1N4148: SMD	72a(3,4mm)	1N4148 SMD	72a(3,4mm)	
LS 4150	Si-Di	=1N4150: SMD	72a(3,4mm)	1N4148 SMD	72a(3,4mm)	
LS 4151	Si-Di	=1N4151: SMD	72a(3,4mm)	1N4148 SMD	72a(3,4mm)	
LS 4154	Si-Di	=1N4154: SMD	72a(3,4mm)	1N4148 SMD	72a(3,4mm)	
LS 4448	Si-Di	=1N4448: SMD	72a(3,4mm)	1N4148 SMD	72a(3,4mm)	
LS 4558 NB	OP-IC	Dual, Serie 158	8-DIP	4558/8-D	8-DIP	
LS 4558 NM	OP-IC	=LS 4558 NB: SMD	8-MDIP	4558/8(SMD)	8-MDIP	
LT 1016	Si-N	≈BF 255	7e	BF 255	7d	
LTVG 5	Si-Di	kV-Gl, 5kV, 0,02A	31a	(BY 713)	31a	
LTVG 10	Si-Di	kV-Gl, 10kV, 0,02A	31a	(BY 713)	31a	
LTVG 11	Si-Di	kV-Gl, 11kV, 0,02A	31a	(BY 713)	31a	
LV 4001 W	CMOS-IC	SMD, VC, Chroma-Prozessor (Hi8)	48-MP	-	-	
LV 4101 W	CMOS-IC	SMD, Camera-Prozessor	64-MP	-	-	
LZ....	Z-Di		31a	Z-DiodeV	31a	

M

M 1	Se-Di		31a	(1N4148)	31a	
M 01...10	Si-Br	100...1000V, 2A	33(→→→)	B500C1500	33(→→→)	7
M 2	Si-Di	Gl, Uni, 100V, 1A	71(5mm)	-	-	
M 3	Si-Di	Gl, Uni, 200V, 1A	71(5mm)	-	-	
M 4	Si-Di	Gl, Uni, 400V, 1A	71(5mm)	-	-	
M 5	Si-Di	Gl, Uni, 600V, 1A	71(5mm)	-	-	
M 6	Si-Di	Gl, Uni, 800V, 1A	71(5mm)	-	-	
M 7	Si-Di	Gl, Uni, 1000V, 1A	71(5mm)	-	-	
M 12	Si-Di	Gl, Uni, 100V, 0,2A	31a	BA 159	31a	
M 22	Si-Di	=M 12: 200V	31a	BA 159	31a	
M 30 C60	Se-Di	Dual		(2x 1N4148)	31a	
M 42	Si-Di	=M 12: 400V	31a	BA 159	31a	
M 54 HC00...HCTxx	CMOS-Logic	Standard TTL-Logic(54xx)in CMOS-Techn.		-	-	
M 62	Si-Di	=M 12: 600V	31a	BA 159	31a	
M 74 HC00...HCUxx	CMOS-Logic	Standard TTL-Logic(74xx)in CMOS-Techn.		-	-	
M 74 LSxx...P	TTL-Logic	Standard TTL-Logic 74LS-Serie		-	-	
M 82	Si-Di	=M 12: 800V	31a	BA 159	31a	
M 102	Si-Di	=M 12: 1000V	31a	BA 159	31a	
M 179	Si-N	≈BD 529		BD 237	14h	
M 180	Si-P	≈BD 530		BD 238	14h	
M 193(A,C,D)B1	EAROM-IC	TV, Progr.-Speicher/memory+ctrl.(16Pl.)	28-DIP	-	-	
M 193(A....D)	Si-P	≈BF 450	7e	BF 324	7a	
M 200 E	Ge-P	≈AF 126		AF 239 S	5g	
M 290	Si-P	≈BC 327		BC 327	7a	
M 299	Si-N	≈BC 337		BC 337	7a	
M 490 B1	NMOS-IC	TV, Tuning, Memory(16Pr.), LED-Display	40-DIP	-	-	